# onsemi

# 225 mW SOT-23 Surface Mount

# MMBZ52xxELT1G Series, SZMMBZ52xxELT1G Series

This series of Zener diodes is offered in the convenient, surface mount plastic SOT-23 package. These devices are designed to provide voltage regulation with minimum space requirement. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

## Features

- 225 mW Rating on FR-4 or FR-5 Board
- Zener Voltage Range 2.4 V to 91 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Peak Power 225 W (8 x 20 µs)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- Pb–Free Packages are Available

## **Mechanical Characteristics:**

CASE: Void-free, transfer-molded, thermosetting plastic case FINISH: Corrosion resistant finish, easily solderable MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

**POLARITY:** Cathode indicated by polarity band **FLAMMABILITY RATING:** UL 94 V-0

## MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Power Dissipation @ 20 $\mu s$ (Note 1) @ $T_L \leq 25^\circ C$	P <sub>pk</sub>	225	W
Total Power Dissipation on FR–5 Board, (Note 2) @ T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	556	°C/W
Total Power Dissipation on Alumina Substrate, (Note 3) @ T <sub>A</sub> = 25°C Derated above 25°C	PD	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–65 to +150	°C

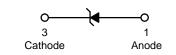
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 9.

2. FR-5 = 1.0 X 0.75 X 0.62 in.

3. Alumina = 0.4 X 0.3 X 0.024 in., 99.5% alumina.

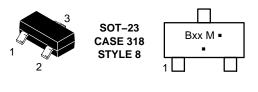




MARKING DIAGRAM

DATA SHEET

www.onsemi.com



Bxx = Device Code

- xx = (Refer to page 2)
- M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBZ52xxELT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SZMMBZ52xxELT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBZ52xxELT3G	SOT–23 (Pb–Free)	10000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

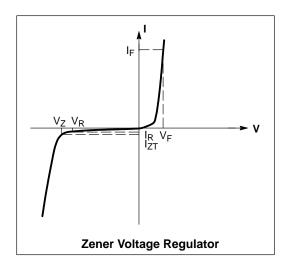
## **DEVICE MARKING INFORMATION**

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

### **ELECTRICAL CHARACTERISTICS**

(Pinout: 1-Anode, 2-No Connection, 3-Cathode) (T<sub>A</sub> = 25°C unless otherwise noted, V<sub>F</sub> = 0.95 V Max. @ I<sub>F</sub> = 10 mA)

Symbol	Parameter
VZ	Reverse Zener Voltage @ IZT
I <sub>ZT</sub>	Reverse Current
Z <sub>ZT</sub>	Maximum Zener Impedance @ I <sub>ZT</sub>
I <sub>ZK</sub>	Reverse Current
Z <sub>ZK</sub>	Maximum Zener Impedance @ I <sub>ZK</sub>
I <sub>R</sub>	Reverse Leakage Current @ V <sub>R</sub>
V <sub>R</sub>	Reverse Voltage
١ <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>



## ELECTRICAL CHARACTERISTICS (Pinout: 1-Anode, 2-NC, 3-Cathode) (V<sub>F</sub> = 0.9 V Max @ I<sub>F</sub> = 10 mA for all types.)

		Z	ener Volta	ige (Note 4	)	Zene	r Impedan	ce	Leakage	Current
	Device		V <sub>Z</sub> (V)		@ I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> (	@ I <sub>ZK</sub>	I <sub>R</sub> @	₽ V <sub>R</sub>
Device*	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μΑ	v
MMBZ5221ELT1/T3G	BE2	2.28	2.4	2.52	20	30	1200	0.25	100	1
MMBZ5226ELT1/T3G	BE7	3.13	3.3	3.47	20	28	1600	0.25	25	1
MMBZ5228ELT1/T3G	BE9	3.70	3.9	4.10	20	23	1900	0.25	10	1
MMBZ5229ELT1/T3G	BF1	4.08	4.3	4.52	20	22	2000	0.25	5	1
MMBZ5230ELT1/T3G	BF2	4.46	4.7	4.94	20	19	1900	0.25	5	2
MMBZ5231ELT1/T3G	BF3	4.84	5.1	5.36	20	17	1600	0.25	5	2
MMBZ5232ELT1/T3G	BF4	5.32	5.6	5.88	20	11	1600	0.25	5	3
MMBZ5234ELT1/T3G	BF6	5.89	6.2	6.51	20	7	1000	0.25	5	4
MMBZ5235ELT1/T3G	BF7	6.46	6.8	7.14	20	5	750	0.25	3	5
MMBZ5236ELT1/T3G	BF8	7.12	7.5	7.88	20	6	500	0.25	3	6
MMBZ5237ELT1/T3G	BF9	7.79	8.2	8.61	20	8	500	0.25	3	6.5
MMBZ5239ELT1/T3G	BG2	8.65	9.1	9.55	20	10	600	0.25	3	7
MMBZ5240ELT1/T3G	BG3	9.50	10	10.50	20	17	600	0.25	3	8
MMBZ5242ELT1/T3G	BG5	11.40	12	12.60	20	30	600	0.25	1	9.1
MMBZ5243ELT1/T3G	BG6	12.35	13	13.65	9.5	13	600	0.25	0.5	9.9
MMBZ5244ELT1/T3G	BG7	13.30	14	14.70	9	15	600	0.25	0.1	10
MMBZ5245ELT1/T3G	BG8	14.25	15	15.75	8.5	16	600	0.25	0.1	11
MMBZ5246ELT1G†	BG9	15.20	16	16.80	7.8	17	600	0.25	0.1	12
MMBZ5248ELT1/T1G	BH2	17.10	18	18.90	7	21	600	0.25	0.1	14
MMBZ5250ELT1/T3G	BH4	19.00	20	21.00	6.2	25	600	0.25	0.1	15

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Zener voltage is measured with a pulse test current  $I_Z$  at an ambient temperature of 25°C.

\*Includes SZ-prefix devices where applicable.

†MMBZ5246EL, MMBZ5252EL, and MMBZ5265EL Not Available in 10,000/Tape & Reel.



		Zener Voltage (Note 5)			Zene	r Impedan	ce	Leakage	Current	
	Device		V <sub>Z</sub> (V)		@ I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> (	⊉ I <sub>ZK</sub>	I <sub>R</sub> @	₽V <sub>R</sub>
Device*	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μΑ	V
MMBZ5252ELT1G†	BH6	22.80	24	25.20	5.2	33	600	0.25	0.1	18
MMBZ5253ELT1/T3G	BH7	23.75	25	26.25	5	35	600	0.25	0.1	19
MMBZ5254ELT1/T3G	BH8	25.65	27	28.35	4.6	41	600	0.25	0.1	21
MMBZ5255ELT1/T3G	BH9	26.60	28	29.40	4.5	44	600	0.25	0.1	21
MMBZ5256ELT1/T3G	BJ1	28.50	30	31.50	4.2	49	600	0.25	0.1	23
MMBZ5257ELT1/T3G	BJ2	31.35	33	34.65	3.8	58	700	0.25	0.1	25
MMBZ5258ELT1/T3G	BJ3	34.20	36	37.80	3.4	70	700	0.25	0.1	27
MMBZ5261ELT1G	BJ6	49.35	47	44.65	2.7	105	1000	0.25	0.1	36
MMBZ5262ELT1/T3G	BJ7	48.45	51	53.55	2.5	125	1100	0.25	0.1	37
MMBZ5263ELT1/T3G	BJ8	53.20	56	58.80	2.2	150	1300	0.25	0.1	43
MMBZ5265ELT1G†	BK1	58.90	62	65.10	2	185	1400	0.25	0.1	47

ELECTRICAL CHARACTERISTICS (continued) (Pinout: 1-Anode, 2-NC, 3-Cathode) (V<sub>F</sub> = 0.9 V Max @ I<sub>F</sub> = 10 mA for all types.)

5. Zener voltage is measured with a pulse test current  $I_Z$  at an ambient temperature of 25°C.

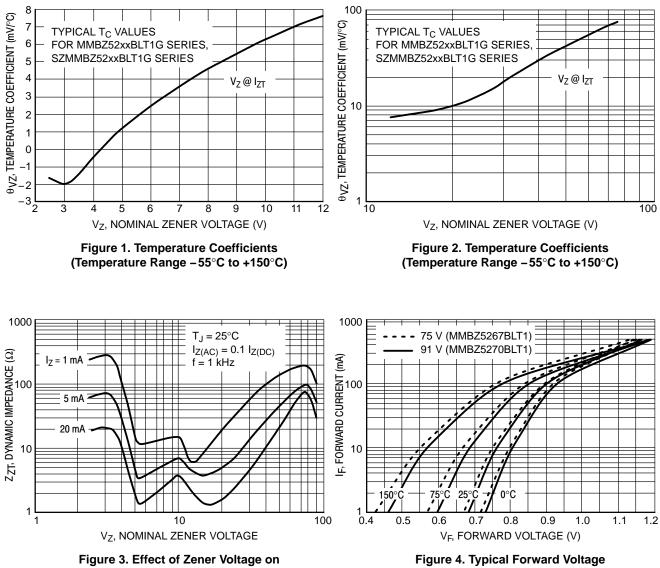
\*Includes SZ-prefix devices where applicable.

†MMBZ5246EL, MMBZ5252EL, and MMBZ5265EL Not Available in 10,000/Tape & Reel.





# **TYPICAL CHARACTERISTICS**



**Zener Impedance** 



#### 1000 1000 IR, LEAKAGE CURRENT (µ.A) 0 V BIAS 1 V BIAS C, CAPACITANCE (pF) 11 00 +150°C\_ BIAS AT 50% OF VZ NOM + 25°C 0.00 55°C 0.0001 1 .00001 100 10 30 40 70 90 10 0 20 50 60 80 1 VZ, NOMINAL ZENER VOLTAGE (V) V<sub>7</sub>, NOMINAL ZENER VOLTAGE (V) Figure 5. Typical Capacitance Figure 6. Typical Leakage Current 100 100 $T_A = 25^{\circ}C$ T<sub>A</sub> = 25°C I<sub>Z</sub>, ZENER CURRENT (mA) .0 1 ZENER CURRENT (mA) 10 1 0.01 0.01 0 2 4 6 8 10 12 10 30 50 70 90 V<sub>Z</sub>, ZENER VOLTAGE (V) V<sub>Z</sub>, ZENER VOLTAGE (V) Figure 8. Zener Voltage versus Zener Current Figure 7. Zener Voltage versus Zener Current (12 V to 91 V) (V<sub>Z</sub> Up to 12 V) 100 PEAK VALUE $I_{RSM} @ 8\,\mu s$ 90 PULSE WIDTH (tp) IS DEFINED 80 AS THAT POINT WHERE THE

# **TYPICAL CHARACTERISTICS**

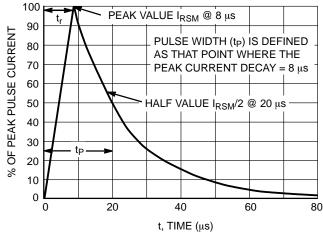


Figure 9. 8  $\times$  20  $\mu s$  Pulse Waveform



# semi



## SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024













XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS							
DIM	MIN	NOM	МАХ				
А	0.89	1.00	1.11				
A1	0.01	0.06	0.10				
b	0.37	0.44	0.50				
с	0.08	0.14	0.20				
D	2.80	2.90	3.04				
E	1.20	1.30	1.40				
е	1.78	1.90	2.04				
L	0.30	0.43	0.55				
L1	0.35	0.54	0.69				
Ηe	2.10	2.40	2.64				
Т	0°		10°				

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **STYLES ON PAGE 2**

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### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CÁSE 318** ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	I	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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